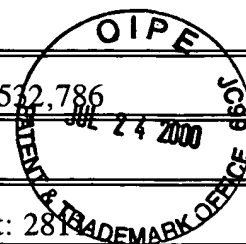


INFORMATION DISCLOSURE CITATION PTO-1449	Atty. Docket No. 000351	Serial No. 09/532,786
	Applicant(s): Nobuhiko Hayashi et al	
	Filing Date: March 22, 2000	Group Art Unit: 2813



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Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
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<u>TN</u> AL	"A Theoretical Analysis of Self-Sustained Pulsation Phenomena in Narrow-Stripe Semiconductor Lasers", <u>IEEE Journal of Quantum Electronics</u> , Vol. 29, No. 5 (May 1993), pp. 1330-1336.

Examiner <u>Phan N. Nguyen</u>	Date Considered <u>7-9-02</u>
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